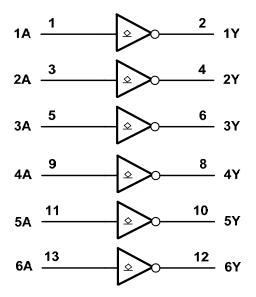


Pin Descriptions

Pin Number	Pin Name	Description	
1	1A	Data Input	
2	1Y	Data Output	
3	2A	Data Input	
4	2Y	Data Output	
5	3A	Data Input	
6	3Y	Data Output	
7	GND	Ground	
8	4Y	Data Output	
9	4A	Data Input	
10	5Y	Data Output	
11	5A	Data Input	
12	6Y	Data Output	
13	6A	Data Input	
14	V _{CC}	Supply Voltage	

Logic Diagram



Function Table

Inputs	Outputs
Α	Y
Н	L
L	Z



Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to +6.5	V
Vı	Input Voltage Range	-0.5 to +6.5	V
Vo	Voltage applied to output in high impedance or IOFF state	-0.5 to +6.5	V
Vo	Voltage applied to output in high or low state	-0.3 to V _{CC} +0.5	V
I _{IK}	Input Clamp Current V _I < 0	-50	mA
I _{OK}	Output Clamp Current V _O < 0	-50	mA
lo	Continuous Output Current	50	mA
	Continuous current through Vdd or GND	±100	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
Ртот	Total Power Dissipation	500	mW

Note: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

Recommended Operating Conditions (Note 5) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit	
V _{CC}	Supply Voltage		1.65	5.5	V	
VI	Input Voltage		0	5.5	V	
V	Output Valtage	Active Mode	0	V_{CC}	V	
Vo	Output Voltage	V _{CC} = 0V; Power Down Mode	0	5.5	V	
Λ±/Λ\/	Innut transition ring or fall rate	V _{CC} = 1.65V to 2.7V		20	no/\/	
Δt/ΔV	Input transition rise or fall rate	V _{CC} = 2.7V to 5.5V		10	ns/V	
T _A	Operating free-air temperature		-40	+125	°C	

Notes: 5. Unused inputs should be held at V_{CC} or Ground.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

0	B	Table Oan didiana		T _A = -40°C	C to +85°C	T _A = -40°C	to +125°C	l lm!t
Symbol	Parameter	Test Conditions	V _{CC}	Min	Max	Min	Max	Unit
			1.65V to 1.95V	0.65 X V _{CC}		0.65 X V _{CC}		
	High-level Input		2.3V to 2.7V	1.7		1.6		V
V_{IH}	Voltage		2.7V to 3.6V	2.0		2.0		V
			4.5V to 5.5V	0.7 X V _{CC}		2.0		
			1.65V to 1.95V		0.35 X V _{CC}		0.35 X V _{CC}	
V _{IL}	Low-level input		2.3V to 2.7V		0.7		0.7	V
VIL	voltage		2.7V to 3.6V		0.8		0.8	V
			4.5V to 5.5V		0.3 X V _{CC}		0.3 X V _{CC}	
	Low-level Output Voltage	I _{OL} = 100μA	1.65V to 5.5V		0.2		0.3	
		I _{OL} = 4mA	1.65V		0.45		0.6	
		I _{OL} = 8mA	2.3V		0.70		0.85	
V_{OL}			2.7V		0.40		0.6	V
	Output Voltage	I _{OL} = 12mA	3.0V		0.55		0.6	
		I _{OL} = 24mA	3.0V		0.55		0.6	
		I _{OL} = 32mA	4.5V		0.55		0.6	
l _{OZ}	Z State Leakage Current	$V_O = GND \text{ or}$ 5.5V	3.6V		±10		±20	μΑ
II	Input Current	V _I =GND to 5.5V	3.6V		± 5		± 20	μA
l _{OFF}	Power Down Leakage Current	V_1 or $V_0 = 0V$ to 3.6V	0		10		20	μΑ
Icc	Supply Current	$V_I = GND \text{ or } V_{CC}$ $I_{O}=0$	3.6V		10		40	μΑ



Switching Characteristics

Symbol	Parameter	Test	V	T,	(= +25°	°C	-40°C to	+85°C	-40°C to	+125°C	Unit
Syllibol	nbol Parameter Cor	Conditions	V _{CC}	Min	Тур	Max	Min	Max	Min	Max	Onit
			1.65V to1.95V	0.3	2.9	5.3	0.3	5.6	0.3	7.6	
		Propagation Delay A _N to Y _N Figure 1	2.3V to 2.7V	0.3	2.6	4.1	0.3	4.7	0.3	5.5	
t _{PLZ} /t _{PZL}			2.7V	0.3	2.5	4.0	0.3	4.5	0.3	5.0	ns
	Delay A _N to Y _N		3V to 3.6V	0.3	2.3	3.5	0.3	3.7	0.3	5.0	
			4.5V to 5.5V	0.3	1.7	2.5	0.3	3.4	0.3	4.5	

Operating Characteristics (@T_A = +25°C, unless otherwise specified.)

	Parameter	Test	V _{CC} = 1.8V	$V_{CC} = 2.5V$	$V_{CC} = 3.3V$	V _{CC} = 5V	Unit	
	rarameter	Conditions Typ		Тур	Тур	Тур	Offic	
C_{pd}	Power dissipation capacitance per gate	f = 10 MHz	7.0	7.5	8.0	8.6	pF	
Cı	Input Capacitance	$V_I = V_{CC} - or$ GND	4	4	4	4	pF	

Package Characteristics

Symbol	Parameter	Test Conditions	V _{cc}	Min	Тур	Max	Unit
0	Thermal Resistance	SO-14	(Note 6)		TBD		°C/W
θ_{JA}	Junction-to-Ambient	TSSOP-14	(Note 6)		159		C/VV
0	Thermal Resistance	SO-14	(Note 6)		TBD		°C/W
θЈС	Junction-to-Case	TSSOP-14	(Note 0)		25		C/VV

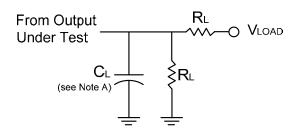
Note: 6. Test condition for SO-14 and TSSOP-14: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

July 2012

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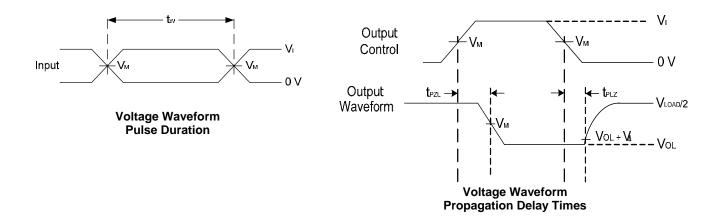


Parameter Measuement Information



TEST	Condition
t _{PLZ} (see Note E)	V_{LOAD}
t _{PZL} (see Note D)	V_{LOAD}

V	Inp	Inputs		V	C	В	V
V _{cc}	VI	t _r /t _f	V _M	V _{LOAD}	CL	R_L	$oldsymbol{V}_\Delta$
1.8V±0.15V	Vcc	≤2ns	V _{CC} /2	2 X V _{CC}	30pF	1ΚΩ	0.15V
2.5V±0.2V	Vcc	≤2ns	V _{CC} /2	2 X V _{CC}	30pF	500Ω	0.15V
2.7V	2.7V	≤2ns	1.5V	6V	50pF	500Ω	0.3V
3.3V±0.3V	3V	≤2.5ns	1.5V	6V	50pF	500Ω	0.3V
5V±0.5V	Vcc	≤2.5ns	V _{CC} /2	2 X V _{CC}	50pF	500Ω	0.3V



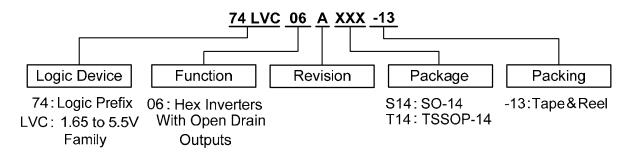
Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.
 C. The inputs are measured one at a time with one transition per measurement.
- D. t_{PZL} is measured at V_M.
- E. $t_{PLZ}\,$ is measured at V_{OL} +V $_{\Delta.}$

Figure 1. Load Circuit and Voltage Waveforms



Ordering Information

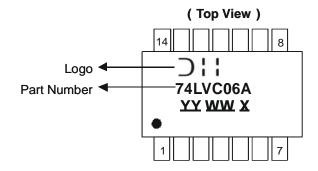


	Device	Package	Packaging	13" Tape and Reel		
	Device	Code	(Note 7)	Quantity	Part Number Suffix	
9	74LVC06AS14-13	S14	SO-14	2500/Tape & Reel	-13	
9	74LVC06AT14-13	T14	TSSOP-14	2500/Tape & Reel	-13	

Notes: 7. The taping orientation and tape details can be found at http://www.diodes.com/datasheets/ap02007.pdf

Marking Information

(1) SO-14, TSSOP-14



YY: Year: 08, 09,10~ WW: Week: 01~52; 52 represents 52 and 53 week

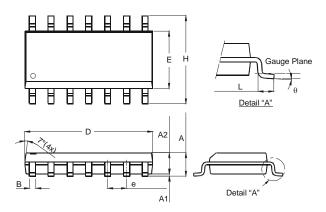
X: Internal Code

Part Number	Package
74LVC06AS14	SO-14
74LVC06AT14	TSSOP-14



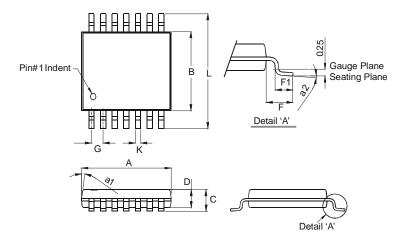
Package Outline Dimensions (All dimensions in mm.)

Package Type: SO-14



SO-14		
Dim	Min	Max
Α	1.47	1.73
A1	0.10	0.25
A2	1.45 Typ	
В	0.33	0.51
D	8.53	8.74
Е	3.80	3.99
е	1.27 Typ	
Η	5.80	6.20
٦	0.38	1.27
θ	0°	8°
All Dimensions in mm		

Package Type: TSSOP-14

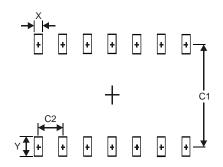


TSSOP-14		
Dim	Min	Max
a1	7° (4X)	
a2	0°	8°
Α	4.9	5.10
В	4.30	4.50
С	_	1.2
D	0.8	1.05
F	1.00 Typ	
F1	0.45	0.75
G	0.65 Typ	
K	0.19	0.30
L	6.40 Typ	
All Dimensions in mm		



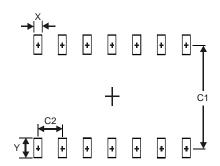
Suggested Pad Layout

Package Type: SO-14



Dimensions	Value (in mm)	
Х	0.60	
Υ	1.50	
C1	5.4	
C2	1 27	

Package Type: TSSOP-14



Dimensions	Value (in mm)
X	0.45
Y	1.45
C1	5.9
C2	0.65

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